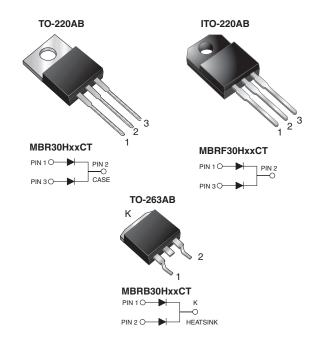


MBR30HxxCT, MBRF30HxxCT, MBRB30HxxCT

Vishay General Semiconductor

Dual Common Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 15 A				
V _{RRM}	35 V, 45 V, 50 V, 60 V				
I _{FSM}	150 A				
V _F	0.56 V, 0.59 V				
I _R	80 μΑ, 60 μΑ				
T _J max.	175 °C				
Package	TO-220AB, ITO-220AB, TO-263AB				
Diode variations	Dual Common Cathode				

FEATURES

- Power pack
- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)							
PARAMETER	SYMBOL	MBR30H35CT MBR30H45CT MBR30H50CT MBR30H60CT					
Maximum repetitive peak reverse voltage	V _{RRM}	35	45	50	60	V	
Working peak reverse voltage	V _{RWM}	35	45	50	60	V	
Maximum DC blocking voltage	V _{DC}	35	45	50	60	V	
Maximum average forward rectified total device	I	30				А	
current (fig. 1) per diode	I _{F(AV)}	15					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150			А		
Peak repetitive reverse surge current per diode at $t_p = 2 \ \mu$ s, 1 kHz	I _{RRM}	1.0 0.5			А		
Peak non-repetitive reverse energy (8/20 μs waveform)	E _{RSM}	25 20		mJ			

Revision: 13-Aug-13

1

Document Number: 88866

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COMPLIANT



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MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	SYMBOL	MBR30H35CT	MBR30H45CT	MBR30H50CT	MBR30H60CT	UNIT	
Non-repetitive avalanche energy per diode at 25 °C, I_{AS} = 4 A, L = 10 mH	E _{AS}	80					
Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 k Ω	V _C	25				kV	
Voltage rate of change (rated V _R)	dV/dt	10 000				V/µs	
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to + 175				°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500				V	

ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	MBR30H35CT MBR30H45CT		MBR30H50CT MBR30H60CT		UNIT
Maximum instantaneous forward voltage per diode ⁽¹⁾	I _F = 15 A	T _C = 25 °C	V _F	-	0.62	-	0.68	V
	I _F = 15 A	T _C = 125 °C		0.49	0.56	0.55	0.59	
	I _F = 30 A	T _C = 25 °C		-	0.73	-	0.83	
	I _F = 30 A	T _C = 125 °C		0.62	0.67	0.68	0.71	
Maximum reverse current per diode at		T _J = 25 °C	1	-	80	-	60	μA
working peak reverse voltage ⁽²⁾		T _J = 125 °C	I _R	5.0	15	4.0	15	mA

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)							
PARAMETER	SYMBOL MBR MBRF MBRB UNIT						
Typical thermal resistance junction to case per diode	$R_{ ext{ heta}JC}$	1.5	4.5	1.5	°C/W		

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	MBR30H45CT-E3/45	1.85	45	50/tube	Tube			
ITO-220AB	MBRF30H45CT-E3/45	1.99	45	50/tube	Tube			
TO-263AB	MBRB30H45CT-E3/45	1.35	45	50/tube	Tube			
TO-263AB	MBRB30H45CT-E3/81	1.35	81	800/teel	Tape and reel			
TO-220AB	MBR30H45CTHE3/45 ⁽¹⁾	1.85	45	50/tube	Tube			
ITO-220AB	MBRF30H45CTHE3/45 (1)	1.99	45	50/tube	Tube			
TO-263AB	MBRB30H45CTHE3/45 ⁽¹⁾	1.35	45	50/tube	Tube			
TO-263AB	MBRB30H45CTHE3/81 (1)	1.35	81	800/teel	Tape and reel			

Note

(1) AEC-Q101 qualified



MBR30HxxCT, MBRF30HxxCT, MBRB30HxxCT

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

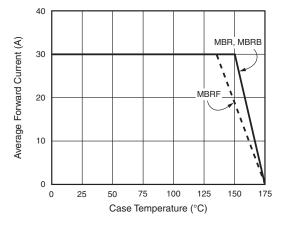


Fig. 1 - Forward Derating Curve

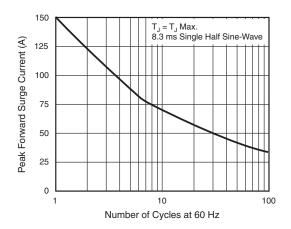


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

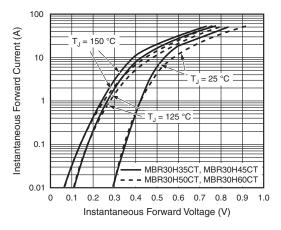


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

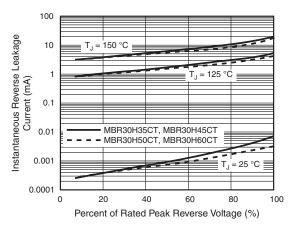


Fig. 4 - Typical Reverse Characteristics Per Diode

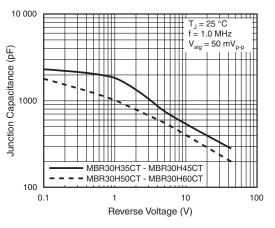


Fig. 5 - Typical Junction Capacitance Per Diode

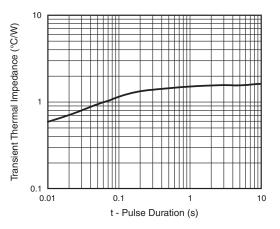


Fig. 6 - Typical Transient Thermal Impedance Per Diode

Revision: 13-Aug-13

3

Document Number: 88866

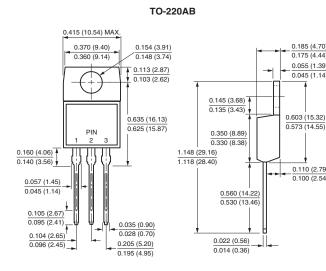
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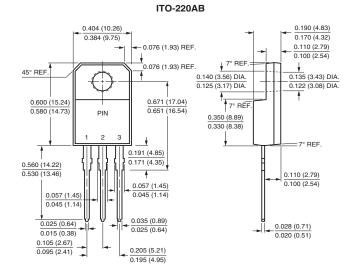


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





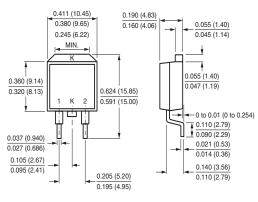
TO-263AB

0.185 (4.70)

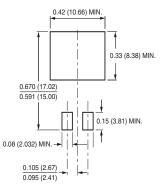
0.055 (1.39)

0.045 (1.14)

0.110 (2.79) 0.100 (2.54)



Mounting Pad Layout



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4



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